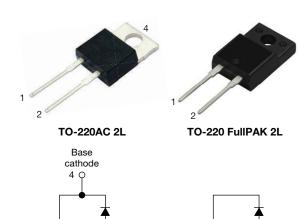
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# VS-ETU1506-M3,VS-ETU1506FP-M3

Vishay Semiconductors

### Ultra Fast Rectifier, 15 A FRED Pt<sup>®</sup>



Cathode Anode

20

Cathode Anode VS-ETU1506FP-M3

20

PRIMARY CHARACTERISTICS					
Package	TO-220AC 2L, TO-220FullPAK 2L				
I <sub>F(AV)</sub>	15 A				
V <sub>R</sub>	600 V				
V <sub>F</sub> at I <sub>F</sub>	1.1 V				
t <sub>rr</sub> (typ.)	24 ns				
T <sub>J</sub> max.	175 °C				
Circuit configuration	Single				

#### **FEATURES**

- Low forward voltage drop
- · Ultrafast soft recovery time
- 175 °C operating junction temperature
- Low leakage current
- Fully isolated package (V<sub>INS</sub> = 2500 V<sub>RMS</sub>)
- True 2 pin package
- Designed and qualified according to JEDEC<sup>®</sup>-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### DESCRIPTION

State of the art, ultralow  $V_F$ , soft-switching ultrafast rectifiers optimized for Discontinuous (Critical) Mode (DCM) Power Factor Correction (PFC).

The minimized conduction loss, optimized stored charge and low recovery current minimized the switching losses and reduce over dissipation in the switching element and snubbers.

The device is also intended for use as a freewheeling diode in power supplies and other power switching applications.

#### APPLICATIONS

AC/DC SMPS 70 W to 400 W

e.g. laptop and printer AC adaptors, desktop PC, TV and monitor, games units and DVD AC/DC power supplies.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Peak repetitive reverse voltage	V <sub>RRM</sub>		600	V			
Average restified featured surrent in DC	I <sub>F(AV)</sub>	T <sub>C</sub> = 151 °C	15	А			
Average rectified forward current in DC		T <sub>C</sub> = 103 °C	15				
Non-repetitive peak surge current	I <sub>FSM</sub>	T <sub>J</sub> = 25 °C	160				
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-65 to +175	°C			

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS MIN. TYP.			MAX.	UNITS	
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>			-	-		
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 15 A	-	1.35	1.9	V	
		I <sub>F</sub> = 15 A, T <sub>J</sub> = 150 °C	-	1.1	1.3		
	-	$V_{R} = V_{R}$ rated	-	0.01	15		
Reverse leakage current I <sub>R</sub>		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	20	200	μA	
Junction capacitance	CT	V <sub>R</sub> = 600 V	-	12	-	pF	
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8	-	nH	

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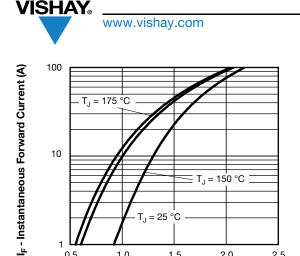
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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$		-	24	28	
Reverse recovery time	+	$I_F = 15 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$		-	36	47	
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	40	-	ns
		T <sub>J</sub> = 125 °C	I <sub>F</sub> = 15 A dI <sub>F</sub> /dt = 200 A/μs V <sub>R</sub> = 390 V	-	87	-	
Poak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	5	-	A
Peak recovery current		T <sub>J</sub> = 125 °C		-	9	-	
	0	T <sub>J</sub> = 25 °C		-	107	-	nC
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	430	-	ne
Reverse recovery time	t <sub>rr</sub>		I <sub>F</sub> = 15 A dI <sub>F</sub> /dt = 800 A/μs	-	53	-	ns
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 125 °C		-	25	-	А
Reverse recovery charge	Q <sub>rr</sub>		V <sub>R</sub> = 390 V	-	730	-	nC

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-65	-	175	°C	
Thermal resistance,	р		-	1.2	1.4		
junction to case FULL-PAK	R <sub>thJC</sub>		-	3.7	4.3		
Thermal resistance, junction to ambient	R <sub>thJA</sub>	Typical socket mount	-	-	70	°C/W	
Typical thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth and greased	-	0.5	-		
			-	2	-	g	
Weight			-	0.07	-	oz.	
Mounting torque			6 (5)	-	12 (10)	kgf · cm (lbf · in)	
Marking davias		Case style TO-220AC 2L	ETU1506				
Marking device		Case style TO-220 FullPAK 2L		ETU1	506FP		

# VS-ETU1506-M3, VS-ETU1506FP-M3



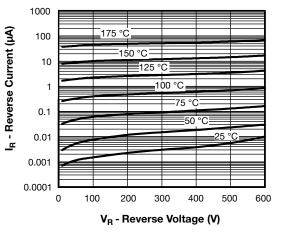


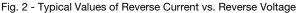
1.5 V<sub>F</sub> - Forward Voltage Drop (V)

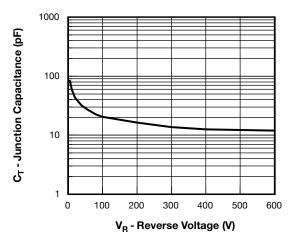
0.5

1.0

Fig. 1 - Typical Forward Voltage Drop Characteristics







2.5

2.0

Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

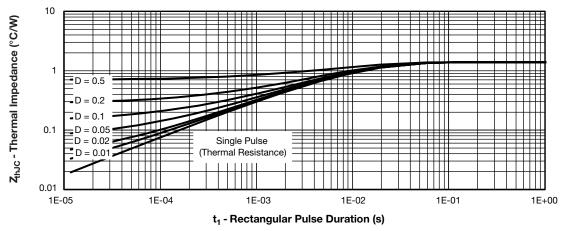
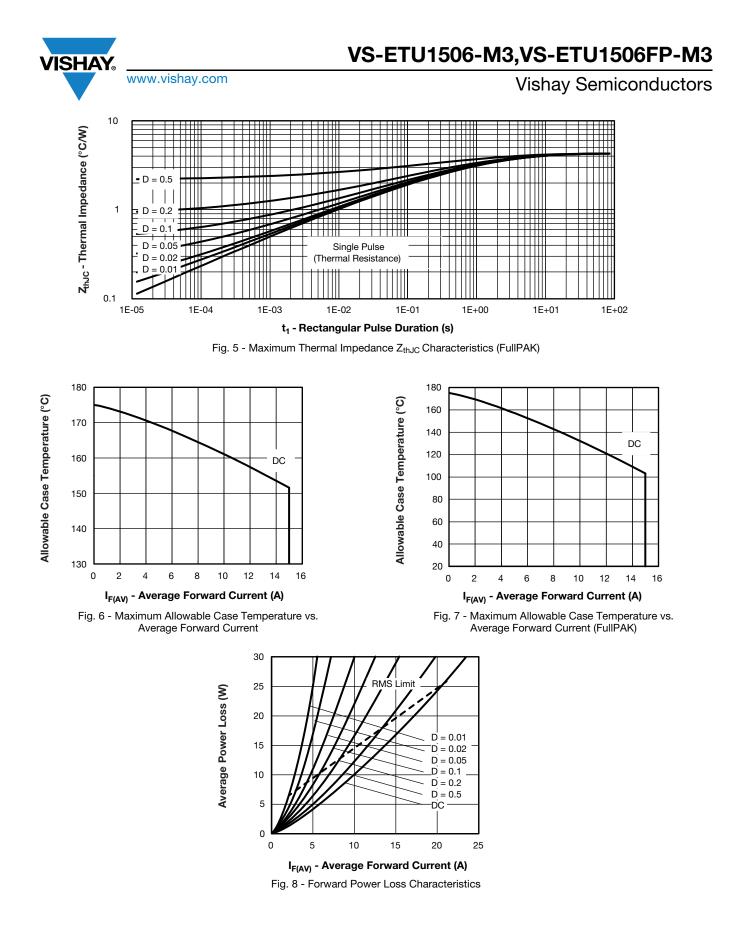
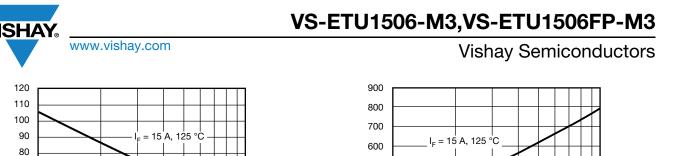


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

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Q<sub>rr</sub> (nC)

t<sub>rr</sub> (ns)

70

60

50

40

30

20

10 100 I<sub>F</sub> = 15 A, 25

typical value

°C

dl<sub>F</sub>dt (A/µs) Fig. 9 - Typical Reverse Recovery vs. dl<sub>F</sub>/dt 500

400

300

200

100

0

100

current during t<sub>b</sub> portion of t<sub>rr</sub>

I<sub>F</sub> = 15 A, 25 °C

dl<sub>F</sub>dt (A/µs)

Fig. 10 - Typical Stored Charge vs. dl<sub>F</sub>/dt

typical value

1000

(3) 0 (4) Q<sub>rr</sub> (2) 0.5 I<sub>RRM</sub>  $I_{RRM}$ dl<sub>(rec)M</sub>/dt (5) 0.75 I<sub>RRM</sub> (1) dl<sub>F</sub>/dt (4)  $Q_{rr}$  - area under curve defined by  $t_{rr}$ (1) dl<sub>F</sub>/dt - rate of change of current and  $I_{\text{RRM}}$ through zero crossing (2) I<sub>RRM</sub> - peak reverse recovery current  $Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$ (3)  $t_{rr}$  - reverse recovery time measured (5)  $dI_{(rec)M}/dt$  - peak rate of change of

1000

from zero crossing point of negative

going I<sub>F</sub> to point where a line passing through 0.75  $\mathrm{I}_{\mathrm{RRM}}$  and 0.50  $\mathrm{I}_{\mathrm{RRM}}$ extrapolated to zero current.

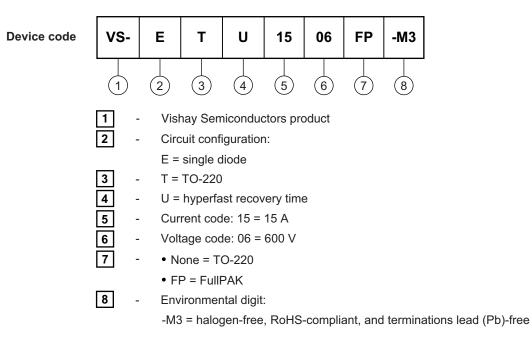
Fig. 11 - Reverse Recovery Waveform and Definitions

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### **ORDERING INFORMATION TABLE**



ORDERING INFORMATION (Example)						
PREFERRED P/N QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTI						
VS-ETU1506-M3	50	1000	Antistatic plastic tube			
VS-ETU1506FP-M3	50	1000	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS					
Dimensions	TO-220AC 2L	www.vishay.com/doc?95259			
Dimensions	TO-220 FullPAK 2L	www.vishay.com/doc?95260			
Part marking information	TO-220AC 2L	www.vishay.com/doc?95391			
	TO-220 FullPAK 2L	www.vishay.com/doc?95392			
SPICE model	TO-220AC 2L	www.vishay.com/doc?96130			
	TO-220 FullPAK 2L	www.vishay.com/doc?96131			

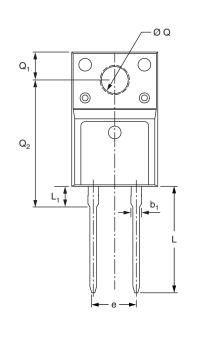


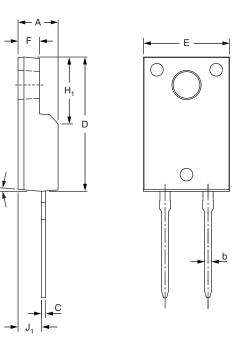


True 2 Pin TO-220 FULL-PAK

θ

### **DIMENSIONS** in millimeters and inches





SYMBOL	MILLIN	METERS	INCHES		
	MIN.	MAX.	MIN.	MAX.	
A	4.53	4.93	0.178	0.194	
b	0.71	0.91	0.028	0.036	
b <sub>1</sub>	1.15	1.39	0.045	0.055	
С	0.36	0.53	0.014	0.021	
D	15.67	16.07	0.617	0.633	
E	9.96	10.36	0.392	0.408	
е	5.08	5.08 typical		typical	
F	2.34	2.74	0.092	0.107	
H <sub>1</sub>	6.50	6.90	0.256	0.272	
J <sub>1</sub>	2.56	2.96	0.101	0.117	
L	12.78	13.18	0.503	0.519	
L <sub>1</sub>	2.23	2.63	0.088	0.104	
ØQ	2.98	3.38	0.117	0.133	
Q <sub>1</sub>	3.10	3.50	0.122	0.138	
Q <sub>2</sub>	14.80	15.20	0.583	0.598	
θ	0°	5°	0°	5°	

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